
# BUK7K12-60E

## Dual N-channel 60 V, 9.3 mΩ standard level MOSFET

11 December 2013 Product data sheet

## 1. General description

Dual standard level N-channel MOSFET in an LFPAK56D (Dual Power-SO8) package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

## 2. Features and benefits

- Dual MOSFET
- Q101 compliant
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True standard level gate with $V_{GS(th)}$ of greater than 1 V at 175 °C

## 3. Applications

- 12 V Automotive systems
- Motors, lamps and solenoid control
- Transmission control
- Ultra high performance power switching

## 4. Quick reference data

**Table 1. Quick reference data**

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|---|
| $V_{DS}$ | drain-source voltage | $T_j \geq 25$ °C; $T_j \leq 175$ °C | | - | - | 60 | V |
| $I_D$ | drain current | $V_{GS}$ = 10 V; Tmb = 25 °C; Fig. 1 | [1] | - | - | 40 | A |
| $P_{tot}$ | total power dissipation | $T_{mb}$ = 25 °C; Fig. 2 | | - | - | 68 | W |
| **Static characteristics FET1 and FET2** | | | | | | | |
| $R_{DSon}$ | drain-source on-state resistance | $V_{GS}$ = 10 V; $I_D$ = 10 A; $T_j$ = 25 °C; Fig. 11 | | - | 7.64 | 9.3 | mΩ |
| **Dynamic characteristics FET1 and FET2** | | | | | | | |
| $Q_{GD}$ | gate-drain charge | $I_D$ = 10 A; $V_{DS}$ = 48 V; $V_{GS}$ = 10 V; $T_j$ = 25 °C; Fig. 13; Fig. 14 | | - | 11 | - | nC |

[1] Continuous current is limited by package.

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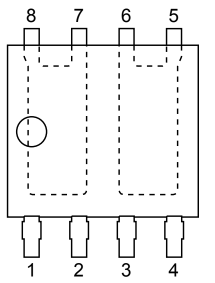
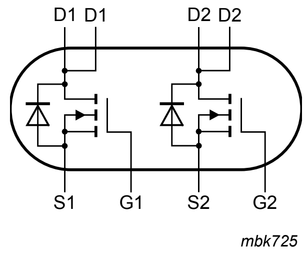
## 5. Pinning information

**Table 2. Pinning information**

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|---|---|---|---|---|
| 1 | S1 | source1 |  LFPAK56D (SOT1205) |  |
| 2 | G1 | gate1 | | |
| 3 | S2 | source2 | | |
| 4 | G2 | gate2 | | |
| 5 | D2 | drain2 | | |
| 6 | D2 | drain2 | | |
| 7 | D1 | drain1 | | |
| 8 | D1 | drain1 | | |

## 6. Ordering information

**Table 3. Ordering information**

| Type number | Package | | |
|---|---|---|---|
| | Name | Description | Version |
| BUK7K12-60E | LFPAK56D | Plastic single ended surface mounted package (LFPAK56D); 8 leads | SOT1205 |

## 7. Marking

**Table 4. Marking codes**

| Type number | Marking code |
|---|---|
| BUK7K12-60E | 71260E |

## 8. Limiting values

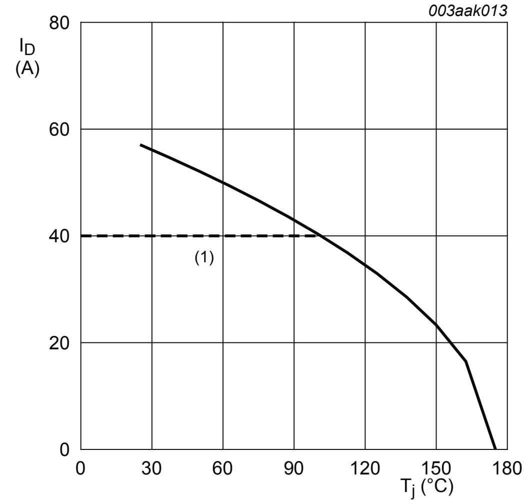
**Table 5. Limiting values**

*In accordance with the Absolute Maximum Rating System (IEC 60134).*

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|---|---|---|---|---|---|---|
| $V_{DS}$ | drain-source voltage | $T_j$ ≥ 25 °C; $T_j$ ≤ 175 °C | | - | 60 | V |
| $V_{DGR}$ | drain-gate voltage | $R_{GS}$ = 20 kΩ | | - | 60 | V |
| $V_{GS}$ | gate-source voltage | $T_j$ ≤ 175 °C; DC | | -20 | 20 | V |
| $I_D$ | drain current | $V_{GS}$ = 10 V; Tmb = 25 °C; Fig. 1 | [1] | - | 40 | A |
| | | $T_{mb}$ = 100 °C; $V_{GS}$ = 10 V; Fig. 1 | [1] | - | 40 | A |
| $I_{DM}$ | peak drain current | $T_{mb}$ = 25 °C; pulsed; $t_p$ ≤ 10 μs; Fig. 4 | | - | 228 | A |
| $P_{tot}$ | total power dissipation | $T_{mb}$ = 25 °C; Fig. 2 | | - | 68 | W |

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|---|---|---|---|---|---|---|
| $T_{stg}$ | storage temperature | | | -55 | 175 | °C |
| $T_j$ | junction temperature | | | -55 | 175 | °C |
| **Source-drain diode FET1 and FET2** | | | | | | |
| $I_S$ | source current | $T_{mb}$ = 25 °C | [1] | - | 40 | A |
| $I_{SM}$ | peak source current | pulsed; $t_p$ ≤ 10 µs; $T_{mb}$ = 25 °C | | - | 228 | A |
| **Avalanche Ruggedness FET1 and FET2** | | | | | | |
| $E_{DS(AL)S}$ | non-repetitive drain-source avalanche energy | $I_D$ = 40 A; $V_{sup}$ ≤ 60 V; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; Fig. 3 | [2][3] | - | 103 | mJ |

[1] Continuous current is limited by package.
[2] Refer to application note AN10273 for further information
[3] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C




(1) Capped at 40A due to package

**Fig. 1. Continuous drain current as a function of mounting base temperature**

$$V_{GS} \geq 10V$$

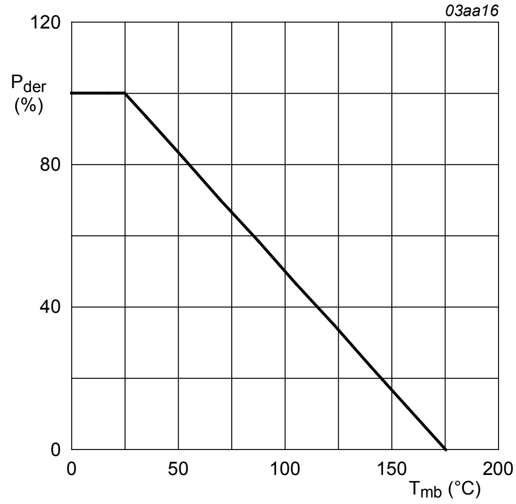



**Fig. 2. Normalized total power dissipation as a function of mounting base temperature**

$$P_{der} = \frac{P_{tot}}{P_{tot(25°C)}} \times 100\,\%$$

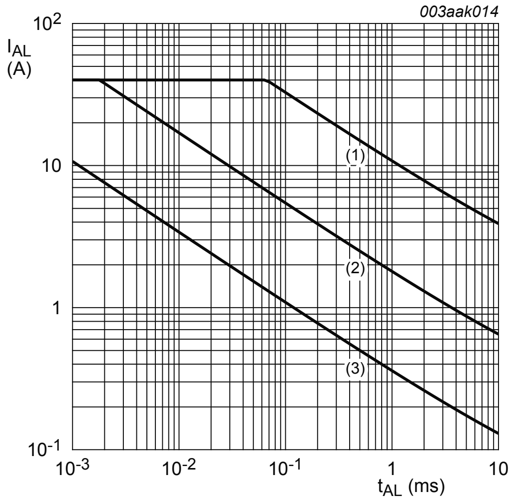



**Fig. 3. Avalanche rating; avalanche current as a function of avalanche time**

(1) $T_{j\ (init)} = 25\,°C$; (2) $T_{j\ (init)} = 150\,°C$; (3) Repetitive Avalanche

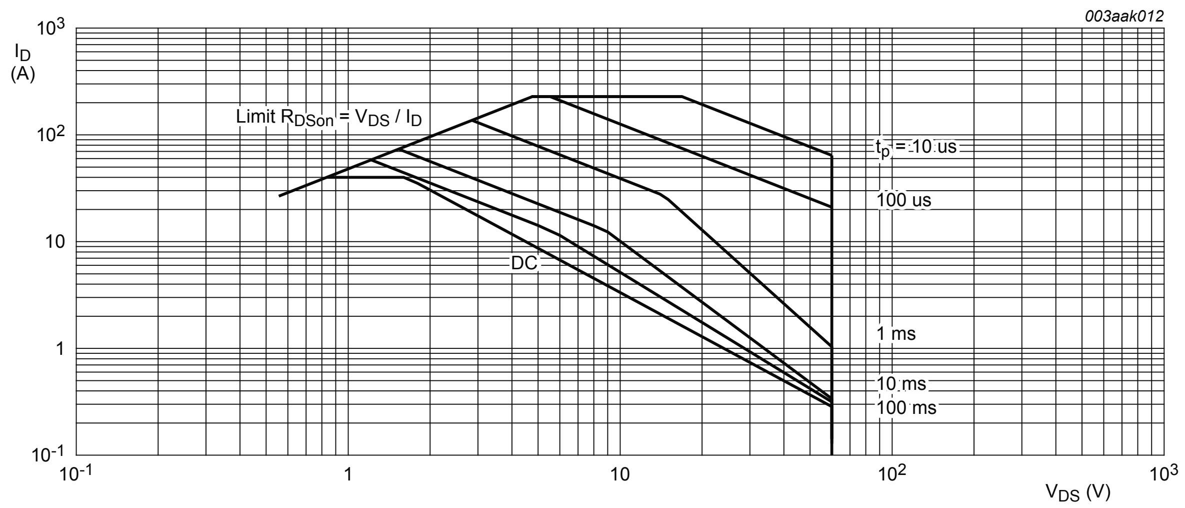



**Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage**

$T_{mb} = 25\,°C$; $I_{DM}$ is a single pulse

## 9. Thermal characteristics

**Table 6. Thermal characteristics**

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|---|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | Fig. 5 | | - | - | 2.21 | K/W |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | Minimum footprint; mounted on a printed circuit board | | - | 95 | - | K/W |

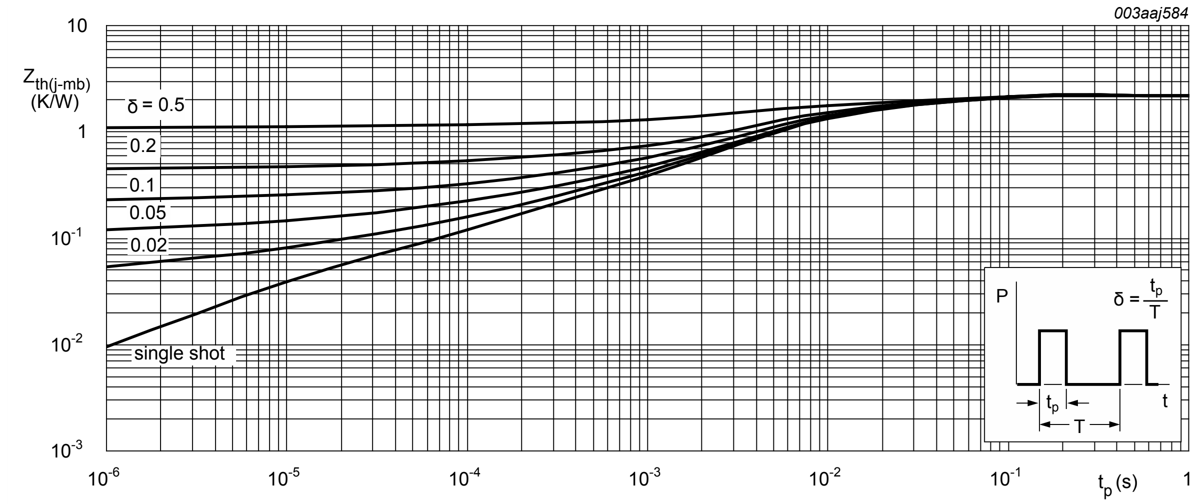


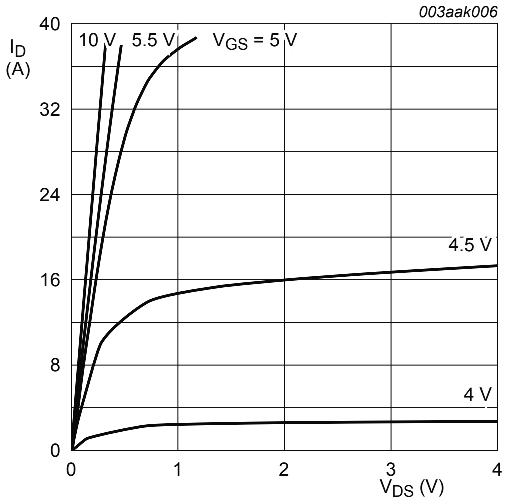

**Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration**

## 10. Characteristics

**Table 7. Characteristics**

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|---|
| **Static characteristics FET1 and FET2** | | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $I_D$ = 250 µA; $V_{GS}$ = 0 V; $T_j$ = -55 °C | | 54 | - | - | V |
| | | $I_D$ = 250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C | | 60 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | $I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$; $T_j$ = 25 °C; Fig. 9; Fig. 10 | | 2.4 | 3 | 4 | V |
| | | $I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$; $T_j$ = 175 °C; Fig. 9; Fig. 10 | | 1 | - | - | V |
| | | $I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$; $T_j$ = -55 °C; Fig. 9; Fig. 10 | | - | - | 4.5 | V |
| $I_{DSS}$ | drain leakage current | $V_{DS}$ = 60 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C | | - | 0.02 | 1 | µA |
| | | $V_{DS}$ = 60 V; $V_{GS}$ = 0 V; $T_j$ = 175 °C | | - | - | 500 | µA |
| $I_{GSS}$ | gate leakage current | $V_{GS}$ = -20 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C | | - | 2 | 100 | nA |
| | | $V_{GS}$ = 20 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C | | - | 2 | 100 | nA |
| $R_{DSon}$ | drain-source on-state resistance | $V_{GS}$ = 10 V; $I_D$ = 10 A; $T_j$ = 25 °C; Fig. 11 | | - | 7.64 | 9.3 | mΩ |
| | | $V_{GS}$ = 10 V; $I_D$ = 10 A; $T_j$ = 175 °C; Fig. 11; Fig. 12 | | - | 17.1 | 20.8 | mΩ |
| **Dynamic characteristics FET1 and FET2** | | | | | | | |
| $Q_{G(tot)}$ | total gate charge | $I_D$ = 10 A; $V_{DS}$ = 48 V; $V_{GS}$ = 10 V; $T_j$ = 25 °C; Fig. 13; Fig. 14 | | - | 34.2 | - | nC |
| $Q_{GS}$ | gate-source charge | | | - | 6.7 | - | nC |
| $Q_{GD}$ | gate-drain charge | | | - | 11 | - | nC |

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|---|
| $C_{iss}$ | input capacitance | $V_{GS}$ = 0 V; $V_{DS}$ = 25 V; f = 1 MHz; $T_j$ = 25 °C; Fig. 15 | | - | 1761 | 2348 | pF |
| $C_{oss}$ | output capacitance | | | - | 247 | 297 | pF |
| $C_{rss}$ | reverse transfer capacitance | | | - | 155 | 213 | pF |
| $t_{d(on)}$ | turn-on delay time | $V_{DS}$ = 48 V; $R_L$ = 5 Ω; $V_{GS}$ = 10 V; $R_{G(ext)}$ = 5 Ω; $T_j$ = 25 °C; $I_D$ = 10 A | | - | 9.1 | - | ns |
| $t_r$ | rise time | | | - | 12.5 | - | ns |
| $t_{d(off)}$ | turn-off delay time | | | - | 23 | - | ns |
| $t_f$ | fall time | | | - | 15 | - | ns |
| **Source-drain diode FET1 and FET2** | | | | | | | |
| $V_{SD}$ | source-drain voltage | $I_S$ = 10 A; $V_{GS}$ = 0 V; $T_j$ = 25 °C; Fig. 16 | | - | 0.78 | 1.2 | V |
| $t_{rr}$ | reverse recovery time | $I_S$ = 10 A; $dI_S/dt$ = -100 A/µs; $V_{GS}$ = 0 V; $V_{DS}$ = 30 V; $T_j$ = 25 °C | | - | 25 | - | ns |
| $Q_r$ | recovered charge | | | - | 24 | - | nC |




$T_j$ = 25 °C; $t_p$ = 300 µs

**Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values**

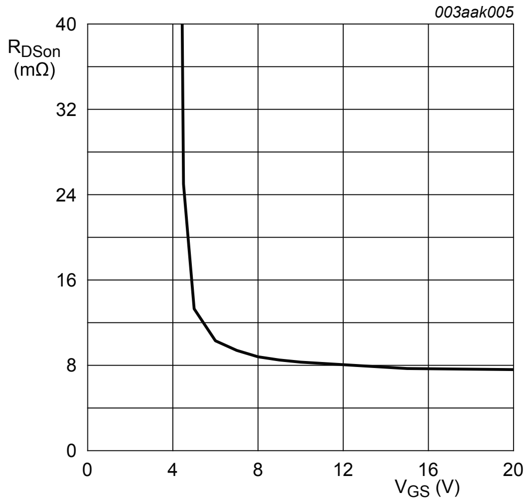



**Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values**

$T_j = 25°C;\ I_D = 10A$

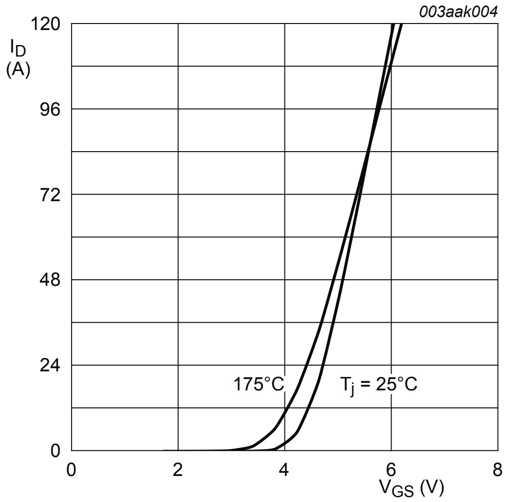



**Fig. 8.** Transfer characteristics; drain current as a function of gate-source voltage; typical values

$V_{DS} = 10 V$

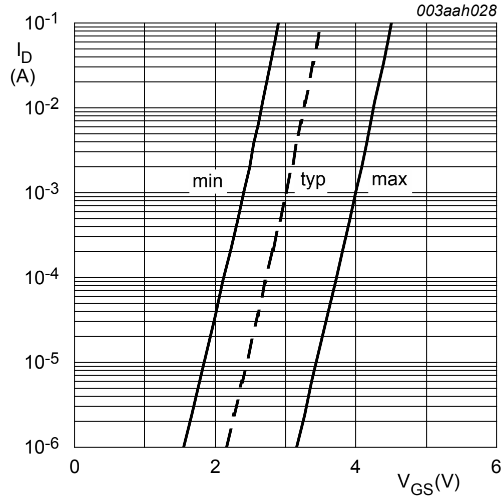



**Fig. 9.** Sub-threshold drain current as a function of gate-source voltage

$T_j = 25 °C;\ V_{DS} = 5 V$

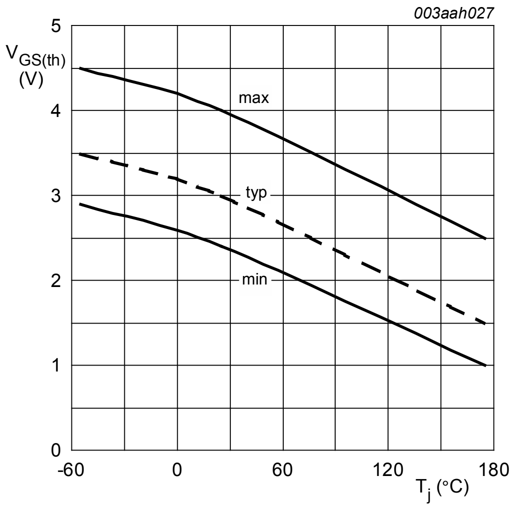
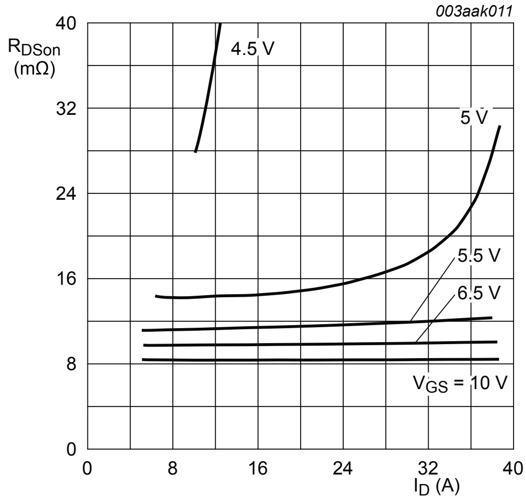



**Fig. 10.** Gate-source threshold voltage as a function of junction temperature

$I_D = 1$ mA; $V_{DS} = V_{GS}$




$T_j$ = 25 °C; $t_p$ = 300 µs

**Fig. 11.** Drain-source on-state resistance as a function of drain current; typical values

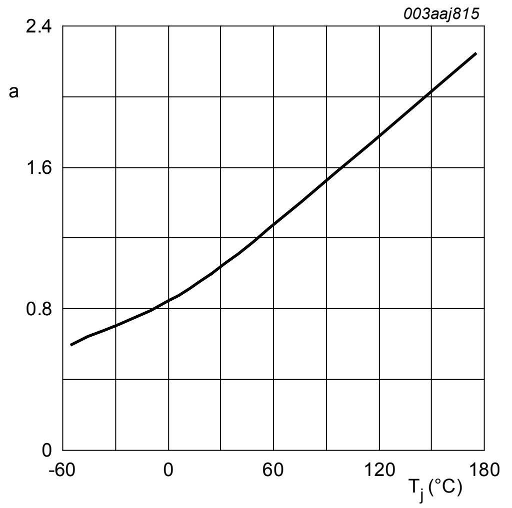



**Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature**

$$a = \frac{R_{DSon}}{R_{DSon\,(25°C)}}$$

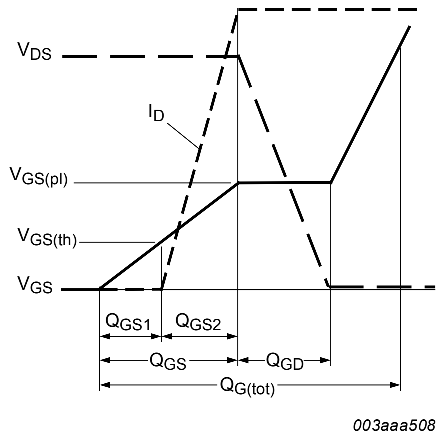



**Fig. 13. Gate charge waveform definitions**

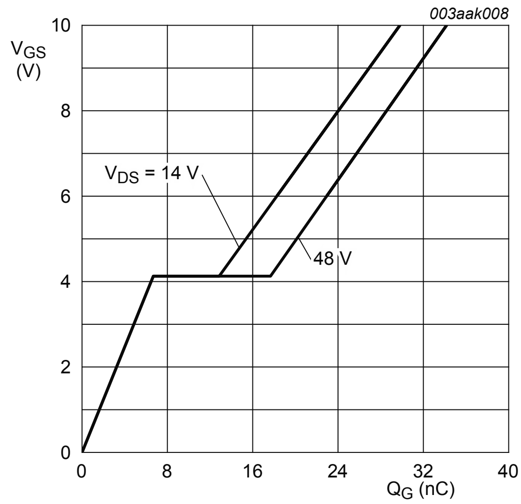



**Fig. 14. Gate-source voltage as a function of gate charge; typical values**

$$T_j = 25°C;\ I_D = 10A$$

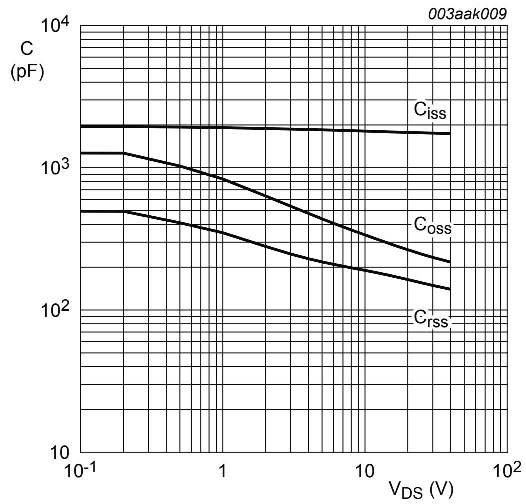



**Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values**

$$V_{GS} = 0V;\ f = 1MHz$$

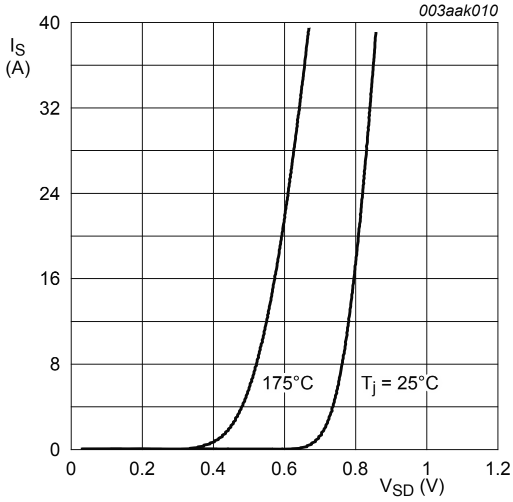
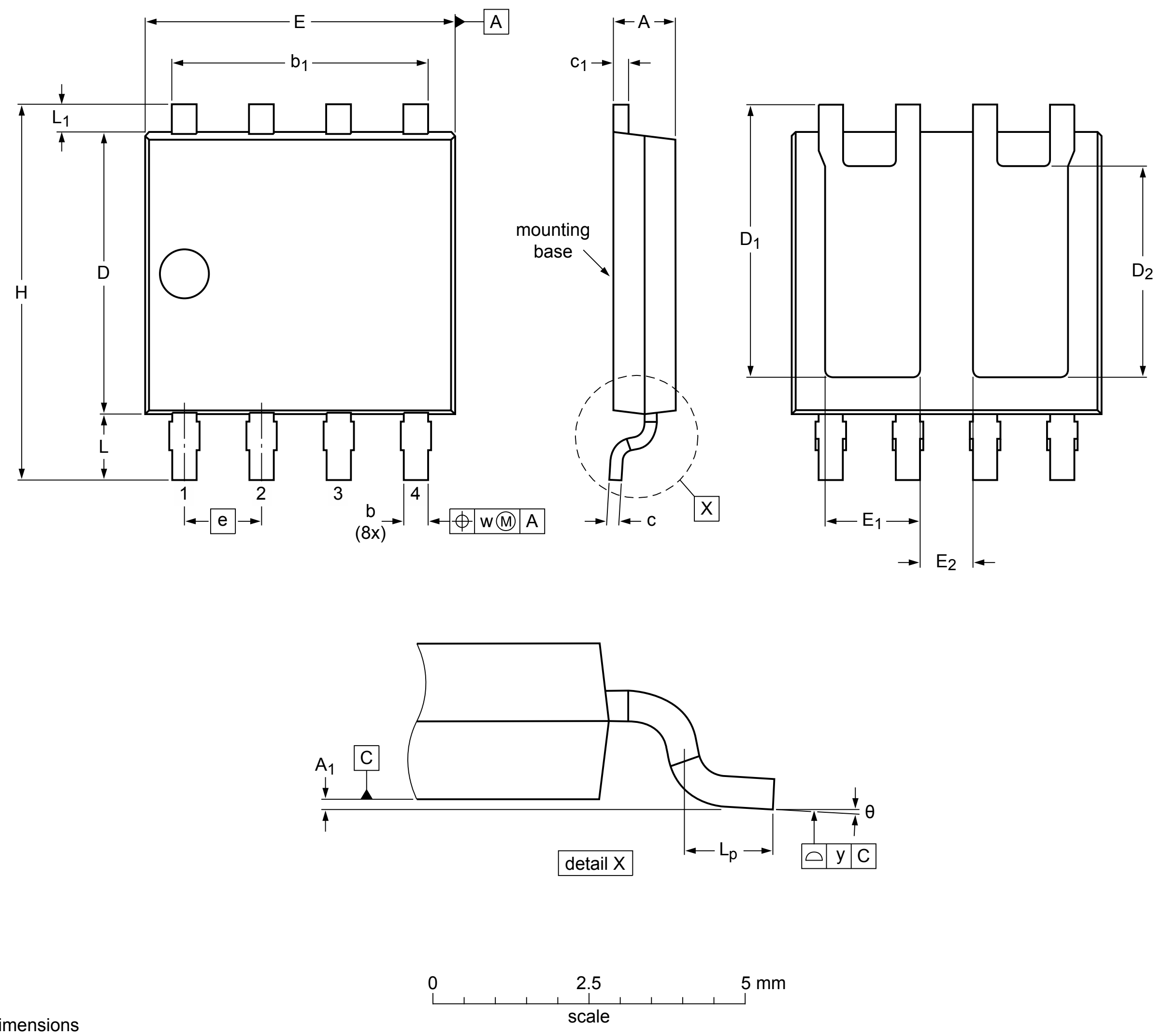



**Fig. 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values**

$V_{GS} = 0 V$

## 11. Package outline

**Plastic single ended surface mounted package (LFPAK56D); 8 leads** **SOT1205**




Dimensions

| Unit | | A | $A_1$ | b | $b_1$ | c | $c_1$ | D(1) | $D_1$(1) | $D_2$ (ref) | E(1) | $E_1$(1) | $E_2$ | e | H | L | $L_1$ | $L_p$ | w | y | θ |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| mm | max | 1.05 | 0.1 | 0.50 | 4.4 | 0.25 | 0.30 | 4.70 | 4.8 | | 5.30 | 1.8 | 0.85 | | 6.2 | 1.3 | 0.55 | 0.85 | | | 8° |
| | nom | | | | | | | | | 3.5 | | | | 1.27 | | | | | 0.25 | 0.1 | |
| | min | | 0.0 | 0.35 | 4.1 | 0.19 | 0.24 | 4.45 | | | 4.95 | 1.6 | | | 5.9 | 0.8 | 0.30 | 0.40 | | | 0° |

Note
1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

*sot1205_po*

| Outline version | References | | | | European projection | Issue date |
|---|---|---|---|---|---|---|
| | IEC | JEDEC | JEITA | | | |
| SOT1205 | | | | | | ~~13-02-19~~<br>13-02-21 |

**Fig. 17. Package outline LFPAK56D (SOT1205)**

# 12. Legal information

## 12.1 Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|---|---|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
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## 13. Contents





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**Date of release: 11 December 2013**